

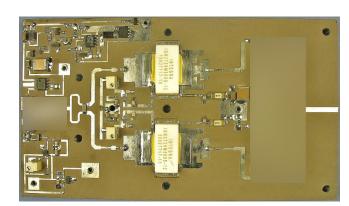
S-Band, GaN/SiC, RF Power Module

2.7 - 2.9 GHz | 1kW typ | 54% Efficiency typ | 12 dB Gain typ | 50 V | 300μs Pulse Length, 10% Duty Cycle

IGNP2729M1KW-GPS is a high power GaN-on-SiC RF power module that has been designed to suit the unique needs of S band radar systems. It operates over the full 2.7 - 2.9 GHz frequency range. Under 300 µs, 10% duty cycle pulse conditions, it supplies a minimum of 1 kW of peak output power, with typically >12 dB of gain and 54% efficiency. It operates from a 50 V supply voltage.

FEATURES

- GaN on SiC HEMT Technology
- Output Power >1 kW
- Fully matched to 50Ω
- High Efficiency up to 54%
- Incorporates Gate Pulsing & Sequencing (GPS) fully automatic, fail-safe bias circuitry
- 100% RF Tested under 300µs, 10% duty cycle pulse conditions



IGNP2729M1KW-GPS Photo

APPLICATIONS

S-band Radar Systems

Table 1. Absolute Maximum Ratings (Not Simultaneous)

Parameter	Symbol	Value	Units	Test Conditions
DC Drain-Source Supply Voltage	V _{DS}	50	V	25 °C
DC Drain Current	I _D	50	A	25 °C
RF Input Power	P _{REIN}	74	W	25 °C
Operating Ambient Temperature	T _{AMB}	-40 to +85	°C	
Storage Temperature	T _{stg}	-55 to +150	°C	
Module Soldering temperature	T _{SOLDER}	260	°C	<50 sec at >200 °C
Operating Junction Temperature	$T_{_{\mathtt{J}}}$	+200	°C	

Note: Operation outside the limits given in this table may cause permanent damage



Table 2. RF Electrical Characteristics (Case temperature = 25 +/- 5 °C unless otherwise stated)

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
RF Ouput Power	P _{out, RF}	1000			W	P _{IN} = 74W
Gain	G	11.3			dB	f = 2.7, 2.8, 2.9 GHz 300μs pulse length, 10% duty cycle
Drain Efficiency	η	50			%	
Input Return Loss	IRL	10			dB	
Pulse Droop	D			-0.6	dB	$V_{DS} = 50V, I_{DS} = 200mA,$
Load Mismatch Stability	VSWR-S	2:1				
VSWR Withstand	VSWR-LMT	3:1				

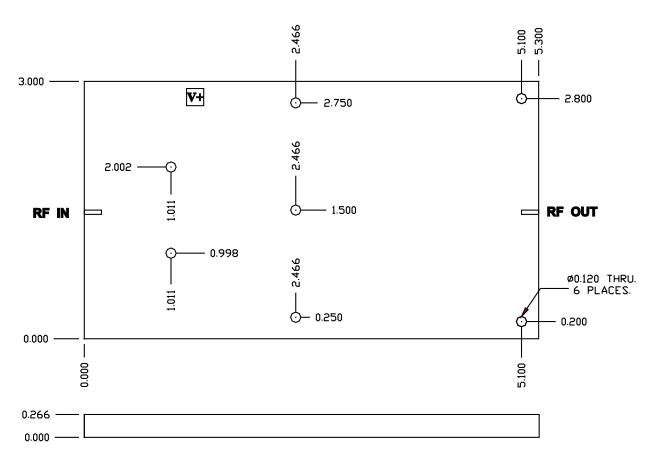
Note: Consult Integra Technologies Application Note 001 for information on how RF output power and pulse droop are measured.

Table 3. Thermal Resistance (Case temperature = 25 °C unless otherwise stated)

Parameter	Symbol	Min	Тур	Test Conditions
Peak Thermal Resistance, Junction to underneath side of module	R _{TH(JC)}		TBD	$P_{OUT} = 1000W$ f = 2.8 GHz $300\mu s pulse length, 10% duty cycle$ $V_{DS} = 50V, I_{DS} = 200mA$



DIMENSIONS (INCHES)





ESD Rating

Parameter	Rating	Standard
ESD Human Body Model (HBM)	TBD	ESDA/JEDEC JS-001-2012
ESD Charged Device Model (CDM)	TBD	JEDEC JESD22-C101F
Moisture Sensitivty Level (MSL)	0	IPC/JEDEC J-STD-020

DEFINITIONS:

DATA SHEET STATUS

Advanced Specification - This data sheet contains Advanced specifications.

Preliminary Specification - This data sheet contains specifications based on preliminary measurements and data.

Final Specification - This data sheet contains final product specifications.

MAXIMUM RATINGS Stress above one or more of the maximum ratings may cause permanent damage to the device. These are maximum ratings only operation of the device at these or at any other conditions above those given in the characteristics sections of the specification is not implied. Exposure to maximum values for extended periods of time may affect device reliability.

DISCLAIMER: Integra Technologies Inc. makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Integra Technologies Inc. assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. Integra Technologies Inc. products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Integra Technologies Inc. customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Integra Technologies Inc. for any damages resulting from such improper use or sale. Copyright @ 2018.

Integra Technologies, 321 Coral Circle, El Segundo, CA 90245-4620 | Phone: 310-606-0855 | Fax: 310-606-0865